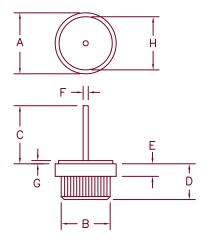
Silicon Power Rectifier R35PF Series



Dim	. Inches		Millimete	•	
	Minimum	Maximum	Minimum	Maximum	Notes
Α	.590	.630	15.0	16.0	Dia.
В	.499	.510	12.6	13.0	Dia.
С	.600		15.2		
D	.350	.370	8.90	9.40	
Ε	.090	.130	2.28	3.30	
F	.045	.053	1.14	1.35	Dia.
G	.030	.035	.762	.900	
Н	.500	.510	12.7	13.0	Dia.

D0-21 (D0-208)

JEDEC	Repetitive Peak Reverse Voltage	
Number		
1N3491, 1N3659	50V	
1N3492, 1N3660	100V	
1N3493, 1N3661	200V	
1N3494, 1N3662	300V	
1N3495, 1N3663	400V	
1N3664	500V	
1N3665	600V	
	Number 1N3491, 1N3659 1N3492, 1N3660 1N3493, 1N3661 1N3494, 1N3662 1N3495, 1N3663 1N3664	

For Reverse Polarity change the "S" prefix of Microsemi part number to "R". Add "R" suffix to the JEDEC part number to specify reverse polarity.

- High Voltage, Low Leakage Current
- Glass Passivated Die
- Soft Recovery
- 400 Amps Surge Rating
- VRRM to 600V

Electrical Characteristics

Average Forward Current (standard polarity) Average Forward Current (reverse polarity)

Maximum Surge Current Maximum I2t For Fusing

Max. Peak Forward Voltage Max. Peak Reverse Current Max. Peak Reverse Current

Max. Recommended Operating Frequency

F(AV) 35 Amps F(AV) 35 Amps FSM400 Amps

I²t 665 A²s

V_{FM 1.1 Volts}

IRM 10 µA ¹RM 2.0 mA 10kHz

 ^{T}C = 133°C, half sine wave, $^{R}\Theta JC$ = 1.0°C/W ^{T}C = 92°C, half sine wave, $^{R}\Theta JC$ = 2.0°C/W

8.3ms, half sine, $T_J = 175$ °C

 $^{1}FM = 35A: ^{T}J = 25^{\circ}C*$

VRRM, TJ = 25°CVRRM, $^{T}J = 150$ °C

*Pulse test: Pulse width 300 µsec. Duty cycle 2%

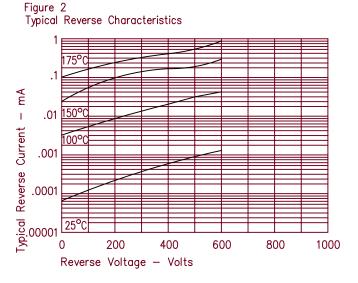
Thermal and Mechanical Characteristics

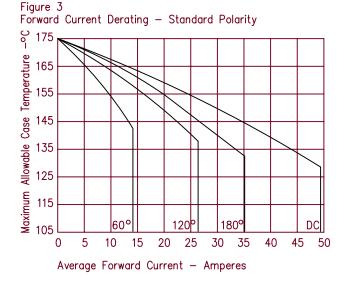
TSTG -65°C to 175°C Storage temp range TJ Operating junction temp range -65°C to 175°C 1.0 °C/W Junction to case 2.0 °C/W Junction to case Rejc Max thermal resistance (standard polarity) Max thermal resistance (reverse polarity) ROJC Recs 0.2°C/W Case to sink Typical thermal resistance Typical Weight 0.3 ounce (9.0 grams) typical

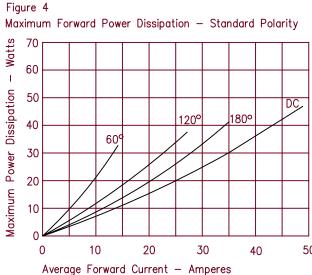


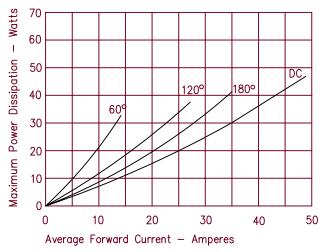
S/R35PF

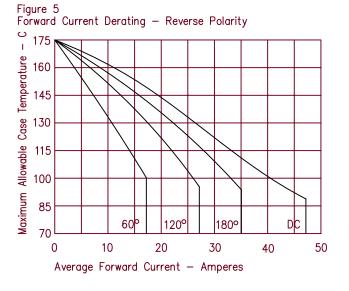
Figure 1 Typical Forward Characteristics 1000 800 600 400 200 100 80 60 40 Instantaneous Forward Current — Amperes 20 175°¢ 25°C 10 8 6 .2 .4 .6 8. 1.0 1.2 1.4 1.6 Instantaneous Forward Voltage - Volts











S/R35PF



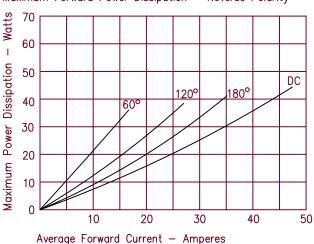
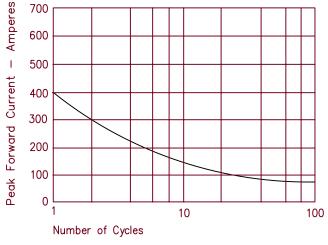


Figure 8 Transient Thermal Impedance - Reverse Polarity 2.1 -°C/Watts 1.8 1.5 1.2 Thermal Impedance Junction to Case .9 .6 .3 0 .001 .01 .1 1 10 100 Time in Seconds

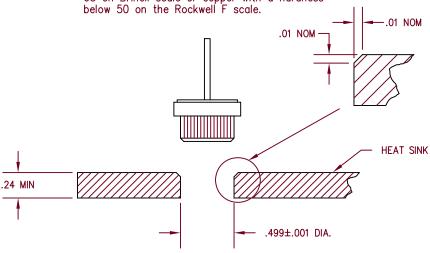
Transient Thermal Impedance - Standard Polarity 1.4 -°C/Watts 1.2 1.0 Thermal Impedance .8 Junction to Case .6 .2 .001 .01 .1 10 100 Time in Seconds





HEAT SINK MOUNTING

The hole edge must be chamfered as shown to avoid shearing off the knurl during press—in. Apply press—in force evenly to avoid tilting. Thermal compound is recommend. Recommended heat sink materials are aluminum with a hardness below 65 on Brinell scale or copper with a hardness below 50 on the Rockwell E scale.



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